TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSⅢ)

## **TPCA8102**

Lithium Ion Battery Applications Notebook PC Applications Portable Equipment Applications

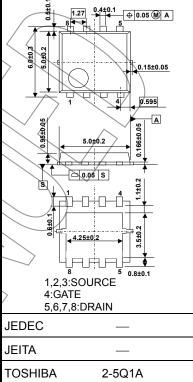
- Small footprint due to small and thin package
- Low drain-source ON resistance:  $RDS(ON) = 4.5m\Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 60S$  (typ.)
- Low leakage current:  $IDSS = -10 \mu A (max) (VDS = -30 V)$
- Enhancement mode:  $V_{th} = -0.8$  to -2.0 V ( $V_{DS} = -10$  V,  $I_{D} = -1$  mA)

## Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	-30	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		V <sub>DGR</sub>	-30	\
Gate-source voltage		VGSS	±20	X
Drain current	DC (Note 1)	ID /	-40	_ A
	Pulsed (Note 1)	TDP	-120	$\supset$ ^
Drain power dissipation	on (Tc=25°C)	PD	45	W
Drain power dissipation (t = 10 s) (Note 2a)		PD	2.8	W
Drain power dissipation (t = 10 s) (Note 2b)		PD	1,6	W
Single pulse avalanche energy (Note 3)		EAS	208	mJ
Avalanche current		) TAR	<b>– 40</b>	Α
Repetitive avalanche energy (Tc=25°C) (Note 4)		EAR	4.5	mJ
Channel temperature		150		°C
Storage temperature range		T <sub>stg</sub>	–55 to 150	°C

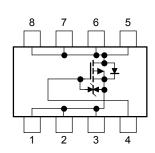
# ⊕ 0.05 M A

Unit: mm



Weight: 0.076 g (typ.)

#### **Circuit Configuration**



Note: For Notes 1 to 4, refer to the next page.

Using continuously under/heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

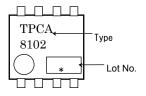
This transistor is an electrostatic-sensitive device.

Please handle with caution.

#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case (Tc=25°C)	R <sub>th (ch-c)</sub>	2.78	°C/W
Thermal resistance, channel to ambient $(t=10 \; s) \eqno(Note \; 2a)$	R <sub>th (ch-a)</sub>	44.6	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	78.1	°C/W

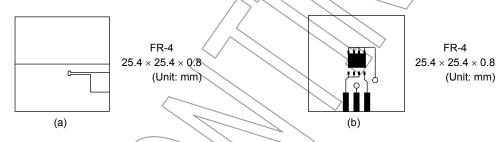
#### Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)

(b) Device mounted on a glass-epoxy board (b)

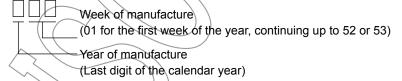


Note 3:  $V_{DD} = 24 \text{ V}$ ,  $T_{ch} = 25^{\circ}\text{C}$  (initial),  $L = 100 \,\mu$  H,  $R_G = 25 \,\Omega$ ,  $I_{AR} = -40 \,\text{A}$ 

Note 4: Repetitive rating: pulse width limited by max channel temperature

Note 5: "O" on the lower left of the marking indicates Pin 1.

\* Weekly code (three digits):



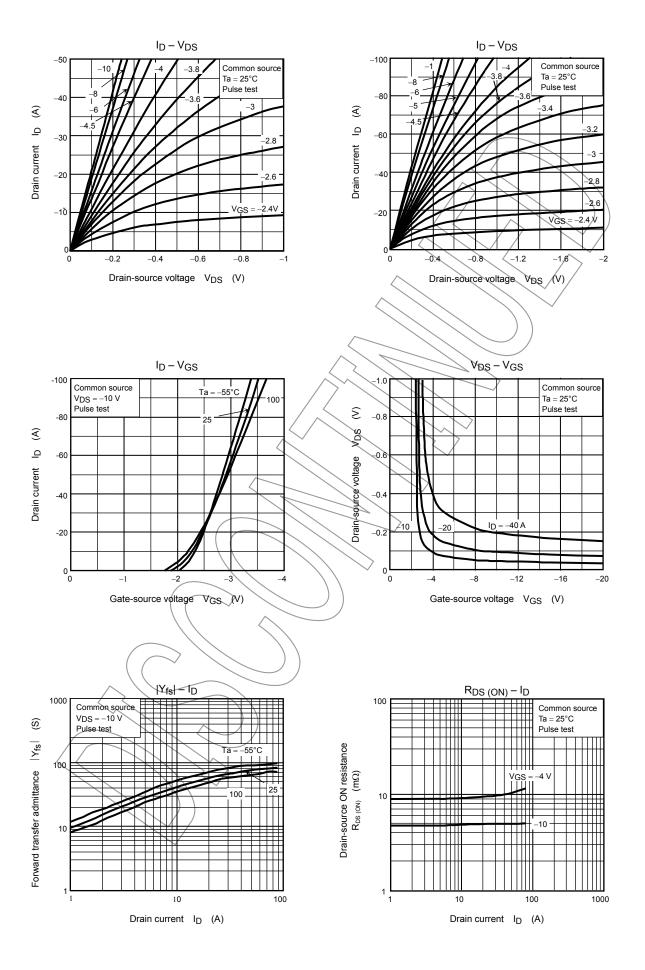
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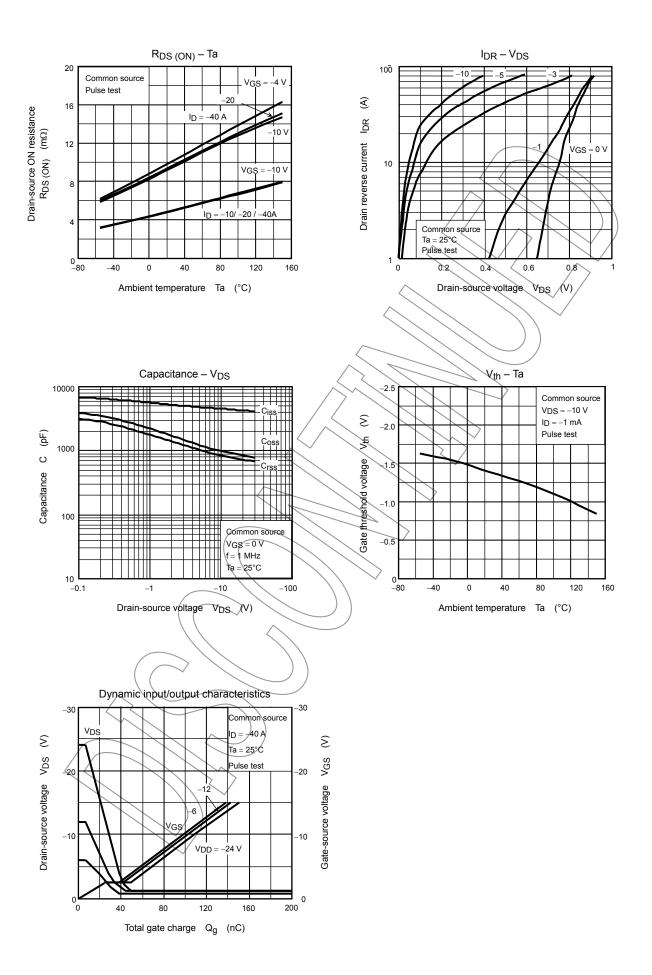
### **Electrical Characteristics (Ta = 25°C)**

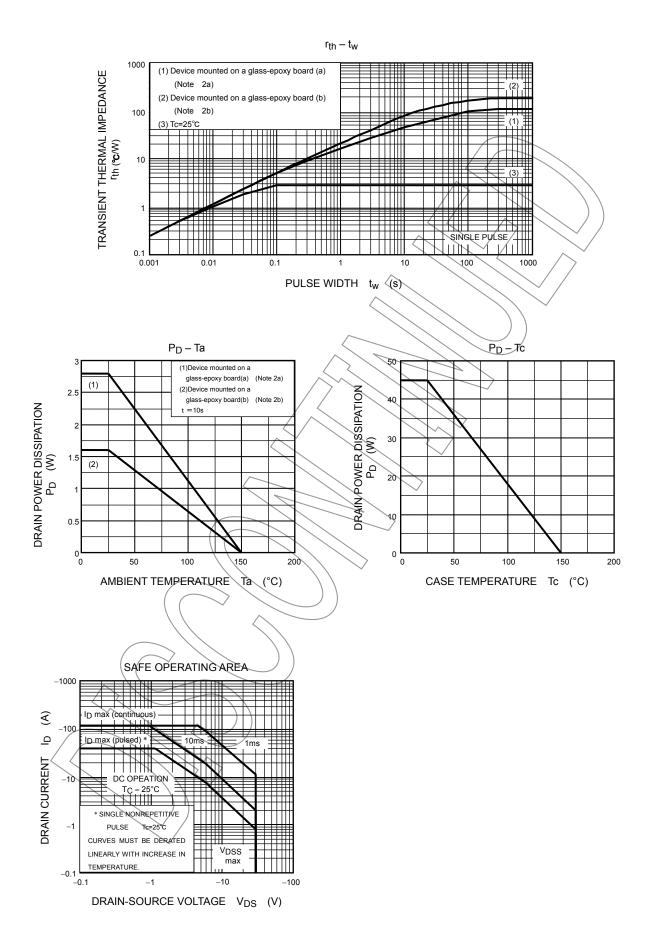
Cha	aracteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μΑ
Drain cut-OFF cu	rrent	I <sub>DSS</sub>	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	-10	μА
Drain-source breakdown voltage		V <sub>(BR)DSS</sub>	$I_D = -10$ mA, $V_{GS} = 0$ V	-30	_		V
		V <sub>(BR)DSX</sub>	$I_D = -10$ mA, $V_{GS} = 20$ V	-15			, v
Gate threshold vo	oltage	V <sub>th</sub>	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$	0.8	1	-2.0	>
Drain-source ON resistance		R <sub>DS</sub> (ON)	$V_{GS} = -4 \text{ V}, I_D = -20 \text{ A}$	/	9.0	14	mΩ
			$V_{GS} = -10 \text{ V}, I_D = -20 \text{ A}$	/	4.5	6.0	
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = -10 \text{ V}, I_D = -20 \text{ A}$	30	60		S
Input capacitance	)	C <sub>iss</sub>		/	4600	\ }	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	¥	850/	,	pF
Output capacitan	ce	Coss			980 /		
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> 0 V   D = -20A	+	10		
	Turn-ON time	t <sub>on</sub>	VGS_10 V VQUT		20		
	Fall time	t <sub>f</sub>	4, 4, 4, 6, 7	>-	78		ns
	Turn-OFF time	t <sub>off</sub>	$V_{DD} \ge -15 \text{ V}$ Duty $\le 1\%$ , $t_W = 10 \text{ µs}$	_	220	_	
Total gate charge (gate-source plus		Qg	$V_{DQ} \simeq -24 \text{ V}, V_{GS} = 10 \text{ V},$		109		
Gate-source char	ge 1	Q <sub>gs1</sub>	$I_{D} = -40 \text{ A}$	_	24	_	nC
Gate-drain ("miller") charge		Qgd			25		

## Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current Pulse (Note 1)	/IDRP	<i>_</i>	_	_	-120	Α
Forward voltage (diode)	VDSF	$I_{DR} = -40 \text{ A}, V_{GS} = 0 \text{ V}$			1.2	V







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